

RNA51957A,B

Voltage Detecting, System Resetting IC Series

REJ03D0912-0100 Rev.1.00 Oct 10, 2008

Description

RNA51957A,B are semiconductor integrated circuits for resetting of all types of logic circuits such as CPUs, and has the feature of setting the detection voltage by adding external resistance.

They include a built-in delay circuit to provide the desired retardation time simply by adding an external capacitor. They fined extensive applications, including battery checking circuit, level detecting circuit and waveform shaping circuit.

Features

- · Few external parts
- Large delay time with a capacitor of small capacitance (td ≈ 100 ms, at 0.33 µF)
- Low threshold operating voltage (Supply voltage to keep low-state at low supply voltage): 0.6 V (Typ) at $R_L = 22 \text{ k}\Omega$
- Wide supply voltage range: 2 V to 17 V
- Wide application range
- Ordering Information

Part Name	Package Type	Package Code	age Code Package Tapin Abbreviation		Surface Treatment
RNA51957AFPH0	SOP-8 pin	PRSP0008DE-C	FP	H (2,500 pcs / Reel)	0 (Ni/Pd/Au)
RNA51957BFPH0	SOP-8 pin	PRSP0008DE-C	FP	H (2,500 pcs / Reel)	0 (Ni/Pd/Au)

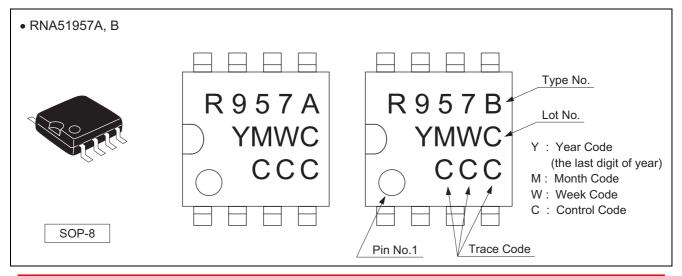
Application

 Reset circuit of Pch, Nch, CMOS, microcomputer, CPU and MCU, Reset of logic circuit, Battery check circuit, switching circuit back-up voltage, level detecting circuit, waveform shaping circuit, delay waveform generating circuit, DC/DC converter, over voltage protection circuit

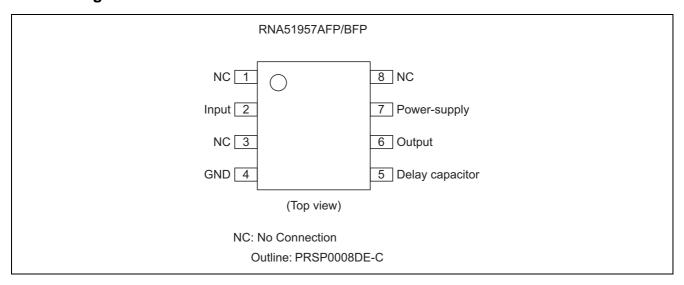
Recommended Operating Condition

• Supply voltage range: 2 V to 17 V

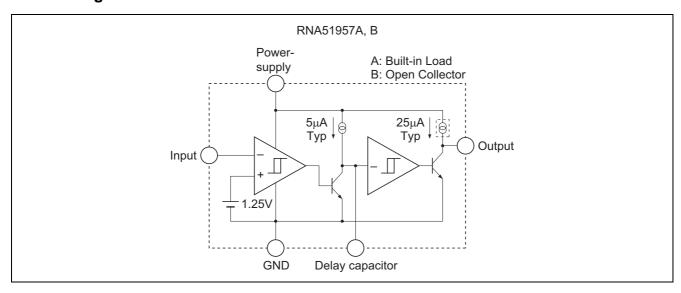
Outline and Article Indication



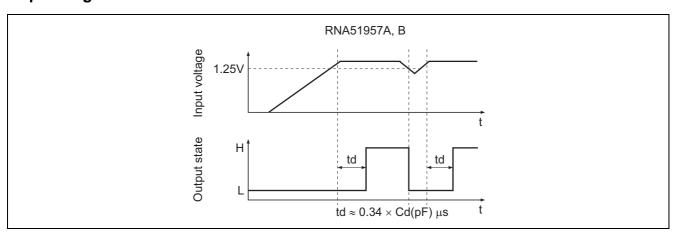
Pin Arrangement



Block Diagram



Operating Waveform



Absolute Maximum Ratings

($Ta = 25^{\circ}C$, unless otherwise noted)

Item	Symbol	Ratings	Unit		Conditions
Supply voltage	V _{CC}	18	V		
Output sink current	Isink	6	mA		
Output voltage	Vo	V _{CC}	V	Type A (output with constant current load)	
Output voltage		18	V	Type B (open collector output)	
Power dissipation	Pd	400	mW	8-pin SOP (PRSP0008DE-C)	
Thermal derating	Kθ	4.4	mW/°C	Refer to the thermal derating curve.	8-pin SOP (PRSP0008DE-C)
Operating temperature	Topr	-40 to +85	°C		
Storage temperature	Tstg	-55 to +125	°C		
Input voltage range	V _{IN}	-0.3 to V _{CC}	V	$V_{CC} \le 7 \text{ V}$	
		–0.3 to +7		$V_{CC} > 7 V$	

Electrical Characteristics

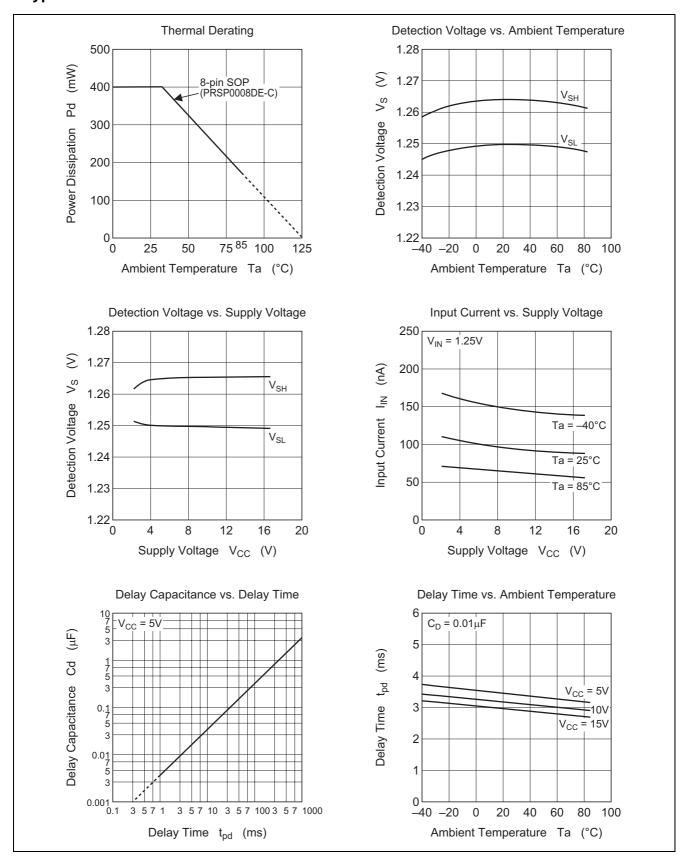
(Ta = 25°C, unless otherwise noted)

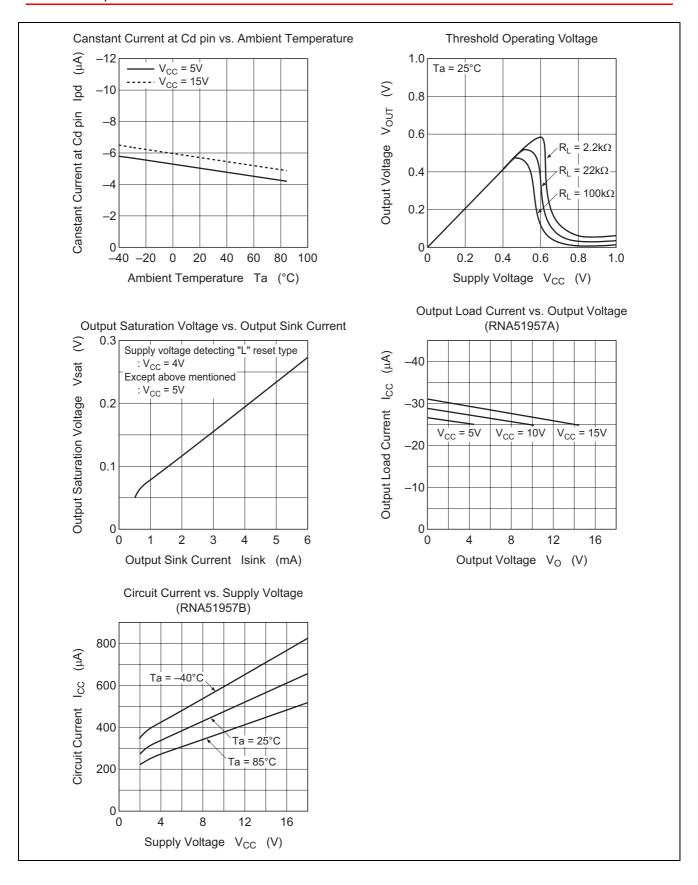
• "L" reset type

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Detecting voltage	Vs	1.20	1.25	1.30	V		
Hysteresis voltage	ΔV_S	9	15	23	mV	$V_{CC} = 5V$	
Detecting voltage temperature coefficient	V _S /ΔT	_	0.01	_	%/°C		
Supply voltage range	V _{cc}	2	_	17	V		
Input voltage range	Vin	-0.3	_	V_{CC}	V	$V_{CC} \le 7V$	
		-0.3	_	7.0	v	V _{CC} > 7V	
Input current	I _{IN}	_	100	500	nA	V _{IN} = 1.25V	
Circuit current	Icc	_	390	590	^	Type A, V _{CC} = 5V	
		_	360	540	μА	Type B, V _{CC} = 5V	
Delay time	t _{pd}	1.6	3.4	7.0	ms	Cd = 0.01µF *	
Output saturation voltage	Vsat	_	0.2	0.4	V	L reset type, $V_{CC} = 5V$, $V_{IN} < 1.2$	V, Isink = 4mA
Threshold operating	V _{OPL}	_	0.67	0.8	V	L reset type minimum supply voltage for IC operation	$R_L = 2.2k\Omega$, $Vsat \le 0.4V$
voltage		_	0.55	0.7			R_L = 100kΩ, Vsat ≤ 0.4V
Output leakage current	I _{OH}	_	_	30	nA	Type B	
Output load current	I _{oc}	-40	-25	-17	μА	Type A, $V_{CC} = 5V$, $V_O = 1/2 \times V_{CC}$	
Output high voltage	V _{OH}	V _{CC} -0.2	V _{CC} -0.06	_	V	Type A	

Note: Please set the desired delay time by attaching capacitor of the range between 4700 pF and 10 μ F.

Typical Characteristics





Example of Application Circuit

Reset Circuit of RNA51957

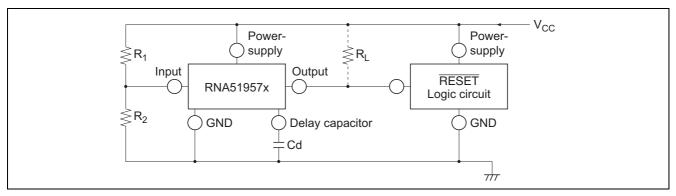


Figure 1 Reset Circuit of RNA51957

Notes: 1. When the detecting supply voltage is 4.25 V, RNA51953 are used. In this case, R_1 and R_2 are not necessary. When the voltage is anything except 4.25 V, RNA51957 are used. In this case, the detecting supply voltage is $1.25 \times (R_1 + R_2)/R_2$ (V) approximately. The detecting supply voltage can be set between 2 V and 15 V.

- 2. If a longer delay time is necessary, RNA51953, RNA51957 are used. In this case, the delay time is about $0.34 \times Cd$ (pF) μs .
- 3. If the RNA51957 and the logic circuit share a common power source, type A (built-in load type) can be used whether a pull-up resistor is included in the logic circuit or not.
- 4. The logic circuit preferably should not have a pull-down resistor, but if one is present, add load resistor R_L to overcome the pull-down resistor.
- 5. When the reset terminal in the logic circuit is of the low reset type, RNA51953 and RNA51957 are used.
- 6. When a negative supply voltage is used, the supply voltage side of RNA51957 and the GND side are connected to negative supply voltage respectively.

Case of Using Reset Signal except Supply Voltage in the RNA51957

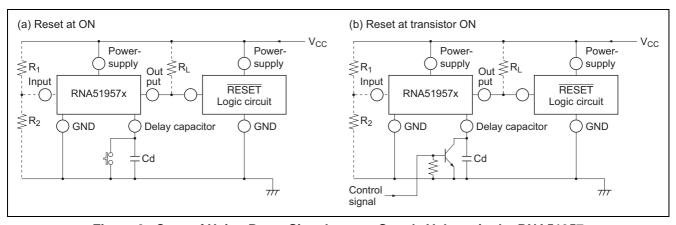


Figure 2 Case of Using Reset Signal except Supply Voltage in the RNA51957

Delay Waveform Generating Circuit

When RNA51957 are used, a waveform with a large delay time can generate only by adding a small capacitor.

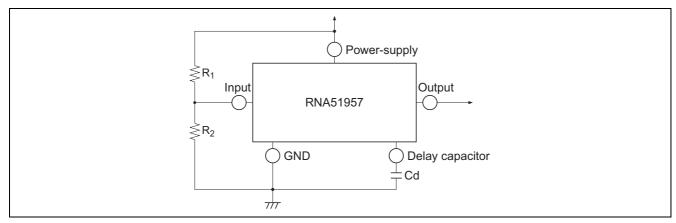


Figure 3 Delay Waveform Generating Circuit

Operating Waveform

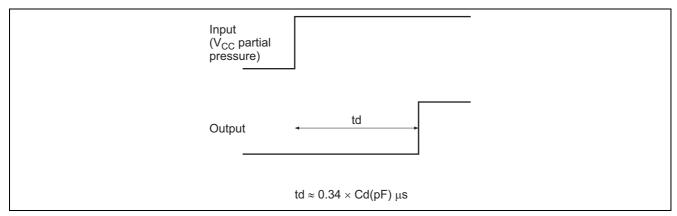


Figure 4 Operating Waveform

Notice for use

About the Power Supply Line

1. About bypass capacitor

Because the ripple and the spike of the high frequency noise and the low frequency are superimposed to the power supply line, it is necessary to remove these.

Therefore, please install C_1 and C_2 for the low frequency and for the high frequency between the power supply line and the GND line as shown in following figure 5.

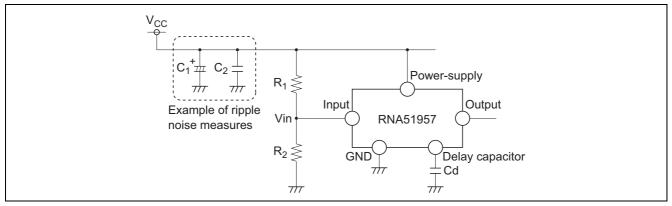


Figure 5 Example of Ripple Noise Measures

2. The sequence of voltage impression

Please do not impress the voltages to the input terminals earlier than the power supply terminal. Moreover, please do not open the power supply terminal with the voltage impressed to the input terminal.

(The setting of the bias of an internal circuit collapses, and a parasitic element might operate.)

About the Input Terminal

1. Setting range of input voltage

The following voltage is recommended to be input to the input terminal (pin 2).

about 0.8 (V) < Vin <
$$V_{CC} - 0.3$$
 (V) ... at $V_{CC} \le 7$ V about 0.8 (V) < Vin < 6.7 (V) at $V_{CC} > 7$ V

2. About using input terminal

Please do an enough verification to the transition characteristic etc. of the power supply when using independent power supply to input terminal (pin 2).

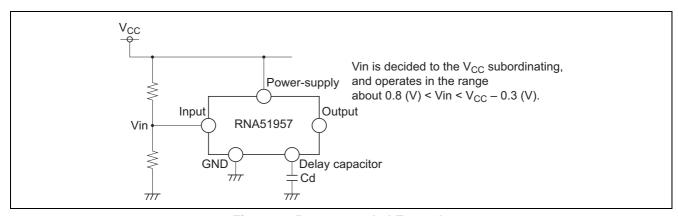


Figure 6 Recommended Example

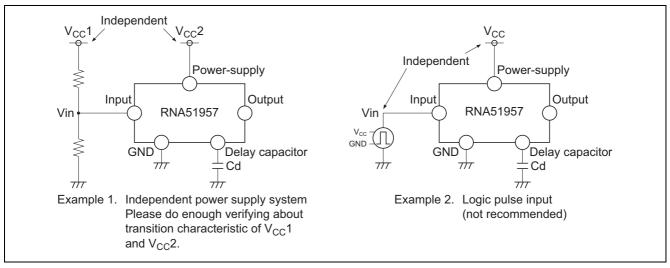


Figure 7

3. Calculation of detecting voltage

Detecting voltage Vs can be calculated by the following expression.

However, the error margin is caused in the detecting voltage because input current Iin (standard 100 nA) exists if it sets too big resistance.

Please set the constant to disregard this error margin.

$$V_S = 1.25 \times \left(\frac{R_1 + R_2}{R_2}\right) + \frac{\text{lin} \times R_1}{\text{error margin}}$$

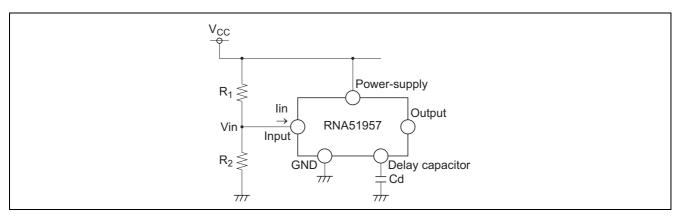


Figure 8 Influence of Input Current

4. About the voltage input outside ratings

Please do not input the voltage outside ratings to the input terminal.

An internal protection diode becomes order bias, and a large current flows.

Setting of Delay Capacity

Please use capacitor Cd for the delay within the range of 10 µF or less.

When a value that is bigger than this is set, the problem such as following (1), (2), and (3) becomes remarkable.

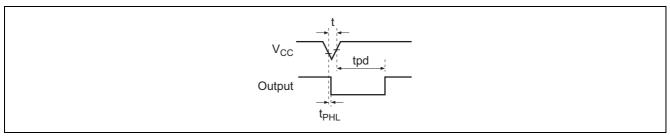


Figure 9 Time Chart at Momentary Voltage-Decrease

(1) The difference at delay time becomes remarkable.

A long delay setting of tens of seconds is fundamentally possible. However, when set delay time is lengthened, the range of the difference relatively grows, too. When a set value is assumed to be 'tpd', the difference occurs in the range from $0.47 \times$ tpd to $2.05 \times$ tpd. For instance, 34 seconds can be calculated at 100 μ F. However, it is likely to vary within the ranges of 16-70 seconds.

(2) Difficulty to react to a momentary voltage decrease.

For example, the reaction time t_{PHL} is 10 µs when delay capacitor Cd = 0.1 µF.

The momentary voltage-decrease that is longer than such t_{PHL} are occurs, the detection becomes possible. When the delay capacitance is enlarged, t_{PHL} also becomes long. For instance, it becomes about 100 to 200 μ s in case of circuit constant $C1 = 100 \ \mu$ F.

(Characteristic graph 1 is used and extrapolation in case of Cd = $100 \mu F$.)

Therefore, it doesn't react to momentary voltage-decrease that is shorter than this.

(3) Original delay time is not obtained.

When the momentary voltage-decrease time 't' is equivalent to t_{PHL} , the discharge becomes insufficient and the charge starts at that state. This phenomenon occurs at large capacitance. And, original delay time tpd is not obtained.

Please refer to characteristic graph 2. (Delay time versus input pulse width)

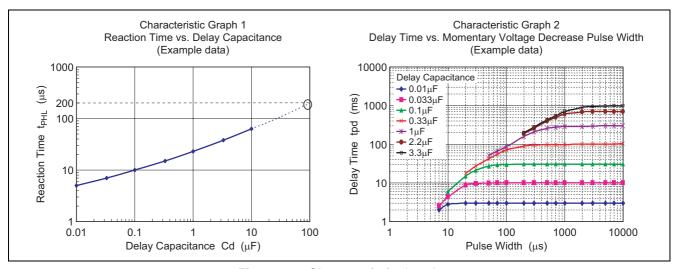


Figure 10 Characteristic Graph

Setting of Output Load Resistance (RNA51957B)

High level output voltage can be set without depending on the power-supply voltage because the output terminal is an open collector type. However, please guard the following notes.

- 1. Please set it in value (2 V to 17 V) within the range of the power-supply voltage recommendation.

 Moreover, please never impress the voltage of maximum ratings 18 V or more even momentarily either.
- 2. Please set output load resistance (pull-up resistance) R_L so that the output current (output inflow current I_L) at L level may become 4 mA or less. Moreover, please never exceed absolute maximum rating (6 mA).

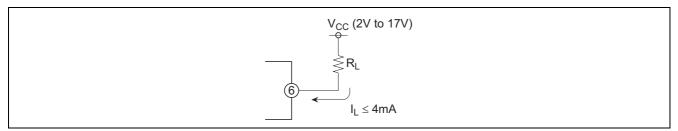
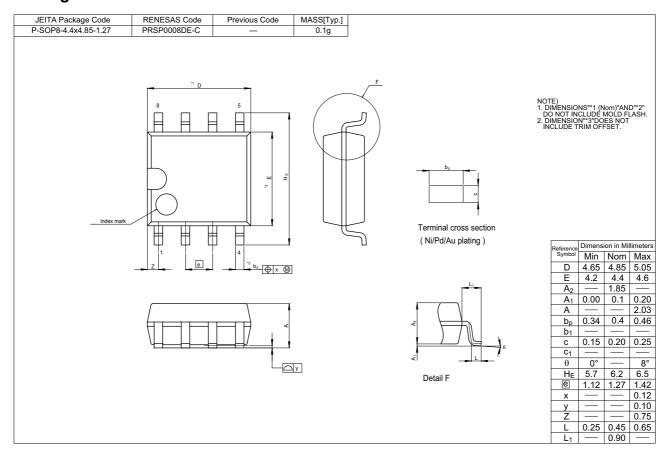


Figure 11 Output Load Resistance R_L

Others

- Notes when IC is handled are published in our reliability handbook, and please refer it.
 The reliability handbook can be downloaded from our homepage (following URL).
 http://www.renesas.com/fmwk.jsp?cnt=reliability_root.jsp&fp=/products/common_info/reliability
- 2. Additionally, please inquire of our company when there is an uncertain point on use.

Package Dimensions



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